

74VCX162240

Low Voltage 16-Bit Inverting Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in Outputs

General Description

The VCX162240 contains sixteen inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX162240 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The 74VCX162240 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD}
 - 3.3 ns max for 3.0V to 3.6V V_{CC}
 - 3.8 ns max for 2.3V to 2.7V V_{CC}
 - 7.6 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
 - ±12 mA @ 3.0V V_{CC}
 - ±8 mA @ 2.3V V_{CC}
 - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V

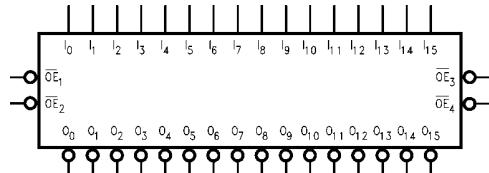
Note 1: To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX162240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

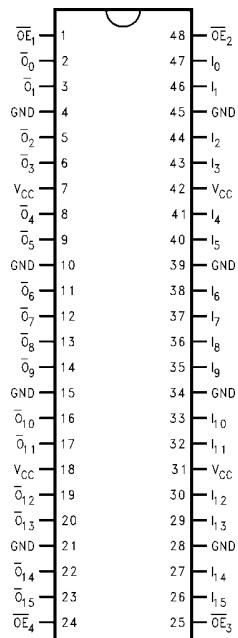
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
\overline{OE}_n	Output Enable Input (Active LOW)
I_0-I_{15}	Inputs
$\overline{O}_0-\overline{O}_{15}$	Outputs

Connection Diagram**Truth Tables**

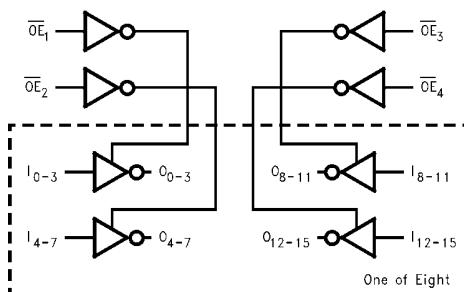
Inputs		Outputs
\overline{OE}_1	I_0-I_3	$\overline{O}_0-\overline{O}_3$
L	L	H
L	H	L
H	X	Z
Inputs		Outputs
\overline{OE}_2	I_4-I_7	$\overline{O}_4-\overline{O}_7$
L	L	H
L	H	L
H	X	Z
Inputs		Outputs
\overline{OE}_3	I_8-I_{11}	$\overline{O}_8-\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z
Inputs		Outputs
\overline{OE}_4	$I_{12}-I_{15}$	$\overline{O}_{12}-\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162240 contains sixteen inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are con-

trolled by an Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram

Absolute Maximum Ratings ^(Note 2)		Recommended Operating Conditions ^(Note 4)			
Supply Voltage (V_{CC})	-0.5V to +4.6V				
DC Input Voltage (V_I)	-0.5V to +4.6V	Power Supply			
Output Voltage (V_O)		Operating	1.65V to 3.6V		
Outputs 3-STATE	-0.5V to +4.6V	Data Retention Only	1.2V to 3.6V		
Outputs Active (Note 3)	-0.5V to V_{CC} +0.5V	Input Voltage	-0.3V to +3.6V		
DC Input Diode Current (I_{IK}) $V_I < 0V$	-50 mA	Output Voltage (V_O)			
DC Output Diode Current (I_{OK})		Output in Active States	0V to V_{CC}		
$V_O < 0V$	-50 mA	Output in 3-State	0.0V to 3.6V		
$V_O > V_{CC}$	+50 mA	Output Current in I_{OH}/I_{OL}			
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA	$V_{CC} = 3.0V$ to 3.6V	±12 mA		
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA	$V_{CC} = 2.3V$ to 2.7V	±8 mA		
Storage Temperature Range (T_{STG})	-65°C to +150°C	$V_{CC} = 1.65V$ to 2.3V	±3 mA		
		Free Air Operating Temperature (T_A)	-40°C to +85°C		
		Minimum Input Edge Rate ($\Delta t/\Delta V$)			
		$V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$	10 ns/V		
Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.					
Note 3: I_O Absolute Maximum Rating must be observed.					
Note 4: Floating or unused inputs must be held HIGH or LOW.					
DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)					
Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max
V_{IH}	HIGH Level Input Voltage		2.7 - 3.6	2.0	
V_{IL}	LOW Level Input Voltage		2.7 - 3.6		0.8
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.7 - 3.6	$V_{CC} - 0.2$	
		$I_{OH} = -6 mA$	2.7	2.2	
		$I_{OH} = -8 mA$	3.0	2.4	
		$I_{OH} = -12 mA$	3.0	2.2	
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7 - 3.6		0.2
		$I_{OL} = 6 mA$	2.7		0.4
		$I_{OL} = 8 mA$	3.0		0.55
		$I_{OL} = 12 mA$	3.0		0.80
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.7 - 3.6		±5.0
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7 - 3.6		±10
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7 - 3.6		20
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 5)	2.7 - 3.6		±20
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750
Note 5: Outputs disabled or 3-STATE only.					

DC Electrical Characteristics ($2.3V \leq V_{CC} \leq 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.3 – 2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -4 mA$	2.3	2.0		V
		$I_{OH} = -6 mA$	2.3	1.8		V
		$I_{OH} = -8 mA$	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.3 – 2.7		0.2	V
		$I_{OL} = 6 mA$	2.3		0.4	V
		$I_{OL} = 8 mA$	2.3		0.6	V
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.3 – 2.7		± 5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		± 10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 6)	2.3 – 2.7		± 20	μA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \leq V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 – 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 – 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	1.65 – 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -3 mA$	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	1.65 – 2.3		0.2	V
		$I_{OL} = 3 mA$	1.65		0.3	V
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	1.65 – 2.3		± 5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 – 2.3		± 10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 – 2.3		20	μA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 7)	1.65 – 2.3		± 20	μA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$, $C_L = 30 \text{ pF}$, $R_L = 500\Omega$						Units	
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$			
		Min	Max	Min	Max	Min	Max		
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.3	1.0	3.8	1.5	7.6	ns	
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	5.1	1.5	9.8	ns	
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.6	1.0	4.0	1.5	7.2	ns	
t_{OSHL} t_{OSLH} (Note 9)	Output to Output Skew		0.5		0.5		0.75	ns	

Note 8: For $C_L = 50\text{pF}$, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

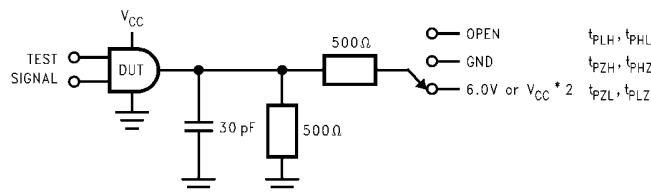
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25^\circ\text{C}$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30 \text{ pF}$, $V_{IH} = V_{CC}$, $V_{IL} = 0\text{V}$	1.8	0.15	V
			2.5	0.25	
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30 \text{ pF}$, $V_{IH} = V_{CC}$, $V_{IL} = 0\text{V}$	1.8	-0.15	V
			2.5	-0.25	
			3.3	-0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30 \text{ pF}$, $V_{IH} = V_{CC}$, $V_{IL} = 0\text{V}$	1.8	1.55	V
			2.5	2.05	
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25^\circ\text{C}$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8, 2.5\text{V or } 3.3\text{V}$, $V_I = 0\text{V or } V_{CC}$	6	pF
C_{OUT}	Output Capacitance	$V_I = 0\text{V or } V_{CC}$, $V_{CC} = 1.8\text{V, } 2.5\text{V or } 3.3\text{V}$	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0\text{V or } V_{CC}$, $f = 10 \text{ MHz}$, $V_{CC} = 1.8\text{V, } 2.5\text{V or } 3.3\text{V}$	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZH}, t_{PLZ}	6V at $V_{CC} = 3.3 \pm 0.3\text{V}$; $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2\text{V}$; $1.8\text{V} \pm 0.15\text{V}$
t_{PZL}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

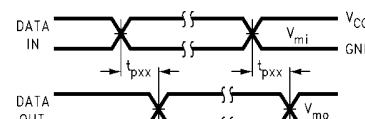


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

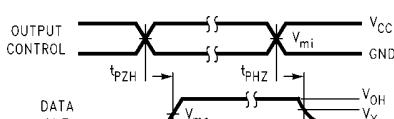


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

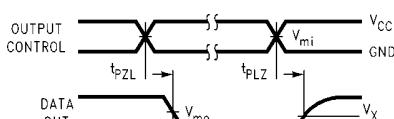
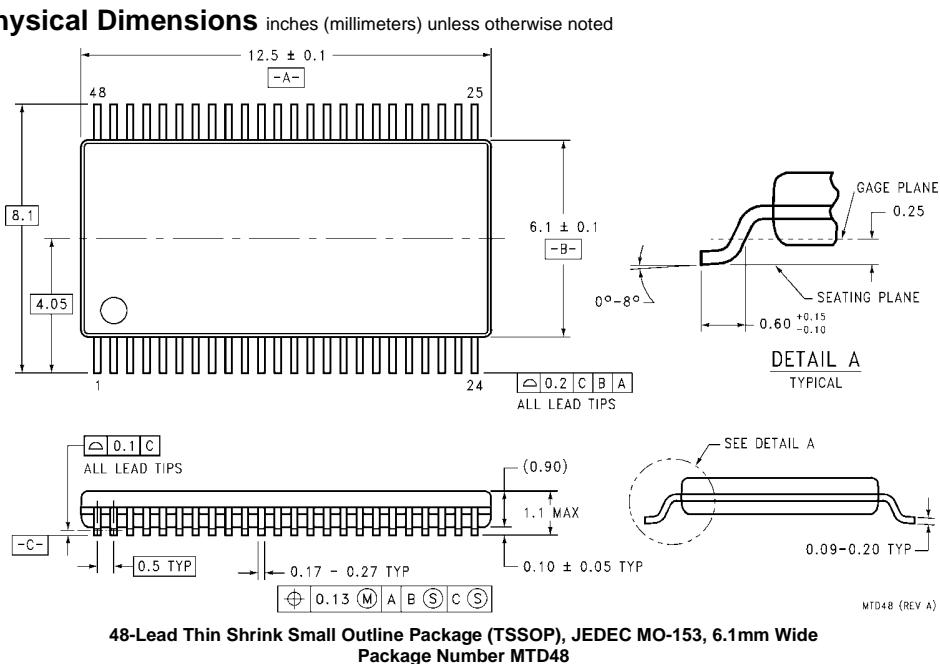


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	$3.3\text{V} \pm 0.3\text{V}$	$2.5\text{V} \pm 0.2\text{V}$	$1.8\text{V} \pm 0.15\text{V}$
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OL} + 0.3\text{V}$	$V_{OL} + 0.15\text{V}$	$V_{OL} + 0.15\text{V}$
V_Y	$V_{OH} - 0.3\text{V}$	$V_{OH} - 0.15\text{V}$	$V_{OH} - 0.15\text{V}$

74VCX162240 Low Voltage 16-Bit Inverting Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in Outputs



LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com